

SCES607B - SEPTEMBER 2004 - REVISED MAY 2013

Single D-Type Flip-Flop with 3-State Output

Check for Samples: SN74LVC1G374-Q1

FEATURES

- Qualified for Automotive Applications
- Supports 5-V V_{CC} Operation
- Inputs Accept Voltages to 5.5 V
- Max t_{pd} of 4 ns at 3.3 V
- Low Power Consumption, 10-µA Max I_{CC}
- ±24-mA Output Drive at 3.3 V
- Ioff Supports Partial-Power-Down Mode
 Operation
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Protection Exceeds JESD 22
 - 2000-V Human-Body Model (A114-A)
 - 200-V Machine Model (A115-A)
 - 1000-V Charged-Device Model (C101)

DESCRIPTION

This single D-type flip-flop is designed for 1.65-V to 5.5-V V_{CC} operation.

The SN74LVC1G374 features a 3-state output designed specifically for driving highly capacitive or relatively low-impedance loads. This device is particularly suitable for implementing buffer registers, input/output (I/O) ports, bidirectional bus drivers, and working registers.

On the positive transition of the clock (CLK) input, the Q output is set to the logic level set up at the data (D) input.

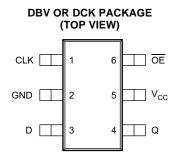
A buffered output-enable (\overline{OE}) input can be used to place the output in either a normal logic state (high or low logic levels) or the high-impedance state. In the high-impedance state, the output neither loads nor drives the bus lines significantly. The high-impedance state and increased drive provide the capability to drive bus lines without interface or pullup components.

 $\overline{\text{OE}}$ does not affect the internal operations of the flipflop. Old data can be retained or new data can be entered while the outputs are in the high-impedance state.

To ensure the high-impedance state during power up or power down, OE should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

To ensure the high-impedance state during power up or power down, OE should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

This device is fully specified for partial-power-down applications using I_{off} . The I_{off} circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.





Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

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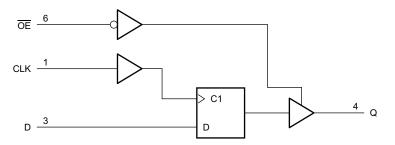


These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

Table 1. FUNCTION TABLE							
	INPUTS						
OE	CLK	OUTPUT Q					
L	↑	L	L				
L	↑	Н	Н				
L	H or L	Х	Q				
Н	Х	Х	Z				

Table 1. FUNCTION TABLE

LOGIC DIAGRAM (POSITIVE LOGIC)



ABSOLUTE MAXIMUM RATINGS

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

			MIN	MAX	UNIT
V _{CC}	Supply voltage range		-0.5	6.5	V
VI	Input voltage range ⁽²⁾		-0.5	6.5	V
V	Voltage range applied to any output	in the high-impedance or power-off state ⁽²⁾	-0.5	6.5	V
Vo	Voltage range applied to any output	in the high or low state ⁽²⁾⁽³⁾	-0.5	V _{CC} + 0.5	V
I _{IK}	Input clamp current, (V _I < 0)		-50	mA	
I _{OK}	Output clamp current, (V _O < 0)			-50	mA
I _O	Continuous output current			±50	mA
	Continuous current through VCC or	GND		±100	mA
•		DBV package		165	°C
θ_{JA}	Package thermal impedance ⁽⁴⁾	DCK package		259	°C
T _{stg}	Storage temperature range		65	150	°C

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

The input and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.

(3) The value of V_{CC} is provided in the recommended operating conditions table.

(4) The package thermal impedance is calculated in accordance with JESD 51-7.

RECOMMENDED OPERATING CONDITIONS⁽¹⁾

			MIN M	AX	UNIT
V	Supply voltage	Operating	1.65	5.5	V
VCC	Supply voltage	Data retention only	1.5		v

 All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.



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RECOMMENDED OPERATING CONDITIONS⁽¹⁾ (continued)

			MIN	MAX	UNIT	
		$V_{CC} = 1.65 \text{ V}$ to 1.95 V	$0.65 - V_{CC}$			
V	Llich lovel input veltage	V_{CC} = 2.3 V to 2.7 V	1.7		V	
VIH	High-level input voltage	$V_{CC} = 3 V$ to 3.6 V	2		v	
		$V_{CC} = 4.5 V \text{ to } 5.5 V$	0.7 – V _{CC}			
		V _{CC} = 1.65 V to 1.95 V				
V		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		0.7	V	
V _{IL}	Low-level input voltage	$V_{CC} = 3 V$ to 3.6 V		0.8	v	
		$V_{CC} = 4.5 V \text{ to } 5.5 V$		$0.3 - V_{CC}$		
VI	Input voltage		0	5.5	V	
Vo	Output voltage		0	V _{CC}	V	
		V _{CC} = 1.65 V		-4		
		V _{CC} = 2.3 V		-8		
	I Pade Laure Laurd and an investor			-16		
I _{OH}	High-level output current	$V_{CC} = 3 V$		-24	mA	
		$V_{CC} = 4.5 V$		-32		
		$V_{CC} = 5 \text{ V}, \text{ T}_{A} = -40^{\circ}\text{C} \text{ to } 85^{\circ}\text{C}$		-40		
		V _{CC} = 1.65 V		4		
		V _{CC} = 2.3 V		8		
	Law law law daw dawa ang			16	mA	
I _{OL}	Low-level output current	$V_{CC} = 3 V$		24		
		$V_{CC} = 4.5 V$		32		
		$V_{CC} = 5 \text{ V}, \text{ T}_{A} = -40^{\circ}\text{C} \text{ to } 85^{\circ}\text{C}$		40		
		V _{CC} = 1.8 V ± 0.15 V, 2.5 V ± 0.2 V		20		
$\Delta t / \Delta v$	Input transition rise or fall rate			10	ns/V	
	•	$V_{CC} = 5 V \pm 0.5 V$			1	
T _A	Operating free-air temperature	· · ·	-40	125	°C	

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INSTRUMENTS

EXAS

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ELECTRICAL CHARACTERISTICS

over recommended operating free-air temperature range (unless otherwise noted)

	TEST CONDITIONS	N N	T _A = −4	0°C to 85°	°C	T _A = −40°C to 12	25°C	
PARAMETER	TEST CONDITIONS	V _{cc}	MIN	TYP ⁽¹⁾	MAX	MIN TYP ⁽¹⁾	MAX	UNI
	I _{OH} = −100 μA	1.65 V to 5.5 V	V _{CC} - 0.1			V _{CC} – 0.1		
	I _{OH} = −4 mA	1.65 V	1.2			1.2		
	I _{OH} = −8 mA	2.3 V	1.9			1.9		
V _{OH}	I _{OH} = −16 mA		2.4			2.4		V
	I _{OH} = −24 mA	3 V	2.3			2.3		
	I _{OH} = −32 mA	4.5 V	3.8			3.8]
	I _{OH} = −40 mA	5 V	4.4					
	I _{OL} = 100 μA	1.65 V to 5.5 V			0.1		0.1	
	I _{OL} = 4 mA	1.65 V			0.45		0.45]
	I _{OL} = 8 mA	2.3 V			0.3		0.3	1
V _{OL}	I _{OL} = 16 mA				0.4		0.5	V
	I _{OL} = 24 mA	3 V			0.55		0.65	1
	I _{OL} = 32 mA	4.5 V			0.55		0.65]
	I _{OL} = 40 mA	5 V			0.513]
I _I	$V_{I} = 5.5 V \text{ or GND}$	0 to 5.5 V			±1		±2	μA
I _{OZ}	$V_0 = 0$ to 5.5 V	1.65 V to 5.5 V			±5		±12	μA
I _{off}	$V_{\rm I}$ or $V_{\rm O}$ = 5.5 V	0			±10		±25	μA
I _{CC}	$V_{I} = 5.5 \text{ V or GND}, I_{O} = 0$	1.65 V to 5.5 V			10		10	μA
ΔI_{CC}	One input at V_{CC} – 0.6 V, Other inputs at V_{CC} or GND	3 V to 5.5 V			500		500	μA
Ci	$V_{I} = V_{CC}$ or GND	3.3 V		3		3	}	pF
Co	$V_0 = V_{CC}$ or GND	3.3 V		6		6	;	pF

(1) All typical values are at V_{CC} = 3.3 V, T_A = 25 ^{\circ}C.

TIMING REQUIREMENTS

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 1)

	1 0	•	0 (,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,						
			V _{CC} = 1.8 V ± 0.15 V		V _{CC} = 2.5 V ± 0.2 V		3 V V	V _{CC} = 5 V ± 0.5 V		UNIT
		MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
f _{clock}	Clock frequency		100		125		150		175	MHz
tw	Pulse duration, CLK high or low	3.3		3		2.8		2.5		ns
t _{su}	Setup time, data before CLK↑	3.5		2.5		2		1.5		ns
t _h	Hold time, data after CLK↑	3.4		1.6		1.5		1.5		ns



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SWITCHING CHARACTERISTICS

over free-air temperature range of -40° C to 85°C, C_L = 30 pF or 50 pF (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	TO	V _{CC} = 1 ± 0.15		V _{CC} = 2 ± 0.2		V _{CC} = 3 ± 0.3		V _{CC} = 5 ± 0.5		UNIT
	(INPUT)	(OUTPUT)	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
f _{max}			100		125		150		175		MHz
t _{pd}	CLK	Q	2.7	18.3	1.8	8.2	1.6	6	1	4	ns
t _{en}	ŌE	Q	2	13	1.5	6.3	0.9	5	0.7	3.5	ns
t _{dis}	OE	Q	2	14	1.1	5.3	1.4	4.5	0.8	3.1	ns

SWITCHING CHARACTERISTICS

over free-air temperature range of -40° C to 125°C, C_L = 30 pF or 50 pF (unless otherwise noted) (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CC} = 1. ± 0.15		V _{CC} = 2 ± 0.2		V _{CC} = 3 ± 0.3		V _{CC} = 5 ± 0.5		UNIT
	(INPUT)	(001901)	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
f _{max}			100		125		150		175		MHz
t _{pd}	CLK	Q	2.7	18.3	1.8	10.2	1.6	7	1	5	ns
t _{en}	OE	Q	2	14	1.5	8.3	0.9	6.5	0.7	5.5	ns
t _{dis}	OE	Q	2	16	1.1	7.3	1.4	6	0.8	5.1	ns

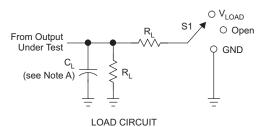
OPERATING CHARACTERISTICS, $T_A = 25^{\circ}C$

PARA	METER	TEST CONDITIONS	V _{CC} = 1.8 V TYP	V _{CC} = 2.5 V TYP	V _{CC} = 3.3 V TYP	V _{CC} = 5 V TYP	UNIT
Power dissipation	Outputs enabled		24	24	25	27	pF
Cpd capacitance	Outputs disabled	f = 10 MHz	8	8	9	11	



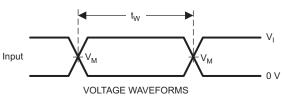
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PARAMETER MEASUREMENT INFORMATION

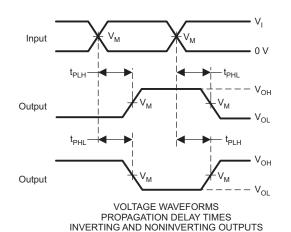


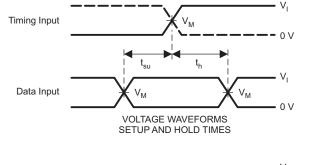
TEST	S1
t _{PLH} /t _{PHL}	Open
t _{PLZ} /t _{PZL}	V _{LOAD}
t _{PHZ} /t _{PZH}	GND

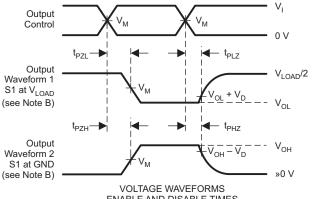
N.	INF	PUTS			-	-	
V _{CC}	VI	t _r /t _f	V _M	V _{LOAD}	CL	RL	V _Δ
1.8 V ± 0.15 V	V _{CC}	≤2 ns	V _{CC} /2	2 × V _{CC}	30 pF	1 kΩ	0.15 V
2.5 V ± 0.2 V	V _{cc}	≤2 ns	V _{CC} /2	$2 \times V_{CC}$	30 pF	500 Ω	0.15 V
3.3 V ± 0.3 V	3 V	≤2.5 ns	1.5 V	6 V	50 pF	500 Ω	0.3 V
5 V ± 0.5 V	V _{cc}	≤2.5 ns	V _{CC} /2	$2 \times V_{CC}$	50 pF	500 Ω	0.3 V



PULSE DURATION







VOLTAGE WAVEFORMS ENABLE AND DISABLE TIMES LOW- AND HIGH-LEVEL ENABLING

NOTES: A. C_L includes probe and jig capacitance.

B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control. C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z_O = 50 Ω .

- D. The outputs are measured one at a time, with one transition per measurement.
- E. t_{PLZ} and t_{PHZ} are the same as $t_{\text{dis}}.$
- F. t_{PZL} and t_{PZH} are the same as $t_{\text{en}}.$

G. t_{PLH} and t_{PHL} are the same as t_{pd}

H. All parameters and waveforms are not applicable to all devices.

Figure 1. Load Circuit and Voltage Waveforms

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REVISION HISTORY

Changes from Revision	A (April 2008) to Revision B
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•	Removed Ordering Information table.	1
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Ų	TEXAS Instruments
Ų	Texas Instruments

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PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
CLVC1G374QDBVRQ1	ACTIVE	SOT-23	DBV	6	3000	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 125	CA4O	Samples
CLVC1G374QDCKRQ1	ACTIVE	SC70	DCK	6	3000	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 125	D4O	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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PACKAGE OPTION ADDENDUM

6-Feb-2020

OTHER QUALIFIED VERSIONS OF SN74LVC1G374-Q1 :

• Catalog: SN74LVC1G374

NOTE: Qualified Version Definitions:

• Catalog - TI's standard catalog product

PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CLVC1G374QDBVRQ1	SOT-23	DBV	6	3000	179.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
CLVC1G374QDCKRQ1	SC70	DCK	6	3000	179.0	8.4	2.2	2.5	1.2	4.0	8.0	Q3

TEXAS INSTRUMENTS

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PACKAGE MATERIALS INFORMATION

3-Aug-2017



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CLVC1G374QDBVRQ1	SOT-23	DBV	6	3000	203.0	203.0	35.0
CLVC1G374QDCKRQ1	SC70	DCK	6	3000	203.0	203.0	35.0

DBV0006A



PACKAGE OUTLINE

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.2. This drawing is subject to change without notice.3. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.

- 4. Leads 1,2,3 may be wider than leads 4,5,6 for package orientation. 5. Refernce JEDEC MO-178.



DBV0006A

EXAMPLE BOARD LAYOUT

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

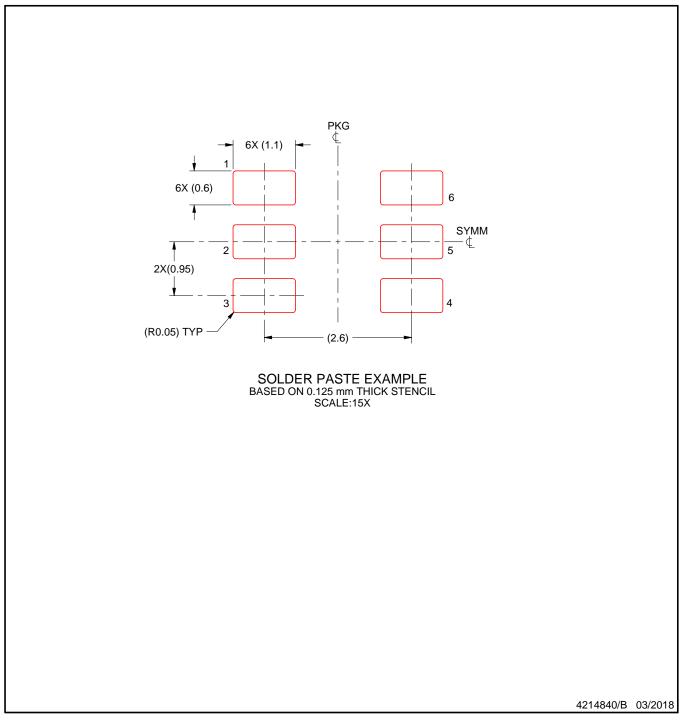


DBV0006A

EXAMPLE STENCIL DESIGN

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

9. Board assembly site may have different recommendations for stencil design.



DCK (R-PDSO-G6)

PLASTIC SMALL-OUTLINE PACKAGE



- NOTES: A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
 - D. Falls within JEDEC MO-203 variation AB.



LAND PATTERN DATA



NOTES:

- A. All linear dimensions are in millimeters.B. This drawing is subject to change without notice.
- C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
- D. Publication IPC-7351 is recommended for alternate designs.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.



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